Preferred Device

Sensitive Gate Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed for high volume, low cost, industrial and consumer applications such as motor control, process control, temperature, light and speed control.

Features

- Small Size
- Passivated Die for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- Surface Mount Lead Form Case 369C
- Epoxy Meets UL 94, V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400 V

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Note 1) (T _J = -40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open) MCR716 MCR718	V _{DRM,} V _{RRM}	400 600	V
On–State RMS Current (180° Conduction Angles; T _C = 90°C)	I _{T(RMS)}	4.0	Α
Average On–State Current (180° Conduction Angles; T _C = 90°C)	I _{T(AV)}	2.6	Α
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T _J = 110°C)	I _{TSM}	25	Α
Circuit Fusing Consideration (t = 8.3 msec)	l ² t	2.6	A ² sec
Forward Peak Gate Power (Pulse Width ≤ 1.0 µsec, T _C = 90°C)	P _{GM}	0.5	W
Forward Average Gate Power (t = 8.3 msec, T _C = 90°C)	P _{G(AV)}	0.1	W
Forward Peak Gate Current (Pulse Width \leq 1.0 µsec, T _C = 90°C)	I _{GM}	0.2	Α
Operating Junction Temperature Range	TJ	-40 to +110	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



ON Semiconductor®

http://onsemi.com

SCRs 4.0 AMPERES RMS 400 – 600 VOLTS



MARKING DIAGRAM



DPAK CASE 369C STYLE 4



Y = Year WW = Work Week x = 6 or 8

PIN ASSIGNMENT			
1	Cathode		
2	Anode		
3	Gate		
4	Anode		

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	3.0	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	80	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

I _{DRM} I _{RRM}		_ _	10 200	μΑ
V_{RGM}	10	12.5	18	V
I _{RGM}	-	-	1.2	μА
V _{TM}	- -	1.3 1.5	1.5 2.2	V
I _{GT}	1.0	25 -	75 300	μΑ
V _{GT}	0.3 - 0.2	0.55 - -	0.8 1.0 –	V
I _H	0.4	1.0	5.0 10	mA
IL	- -	_ _	5.0 10	mA
t _{gt}	_	2.0	5.0	μS
dv/dt	5.0	10	_	V/μs
di/dt	_	-	100	A/μs
	IRRM VRGM IRGM VTM IGT VGT IL tgt	VRGM 10	IRRM	VRGM

- Case 369C, when surface mounted on minimum recommended pad size.
- 3. Ratings apply for negative gate voltage or $R_{GK} = 1 \text{ k}\Omega$. Devices shall not have a positive gate voltage concurrently with a negative voltage on the anode. Devices should not be tested with a constant current source for forward and reverse blocking capability such that the voltage applied exceeds the rated blocking voltage.
 Pulse Test: Pulse Width ≤ 2 ms, Duty Cycle ≤ 2%.
 R_{GK} current not included in measurements.

ORDERING INFORMATION

Device	Package Shipping [†]	
MCR716T4	DPAK	16 mm Tape & Reel (2.5 k / Reel)
MCR718T4	DPAK	16 mm Tape & Reel (2.5 k / Reel)

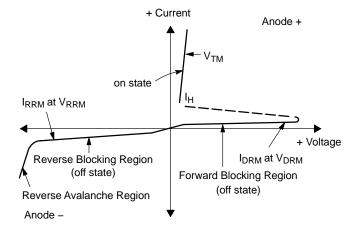
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

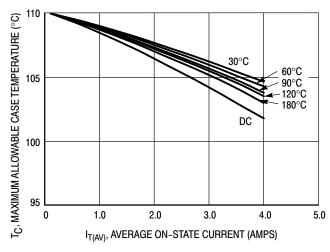
5.0

4.0

Voltage Current Characteristic of SCR

Symbol	Parameter
V _{DRM}	Peak Repetitive Off-State Forward Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Off-State Reverse Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Peak On-State Voltage
lu	Holding Current





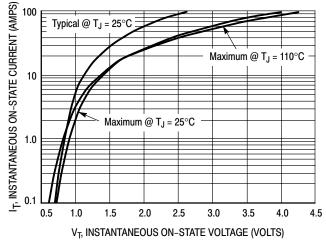
P(AV), AVERAGE POWER DISSIPATION (WATTS) 90°C 3.0 120°C 180°C DC 2.0 1.0 0 1.0 2.0 3.0 5.0 I_{T(AV)}, AVERAGE ON-STATE CURRENT (AMPS)

Figure 1. Average Current Derating

Figure 2. On-State Power Dissipation

30°C

60°C



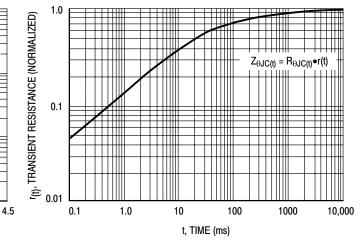


Figure 3. On-State Characteristics

Figure 4. Transient Thermal Response

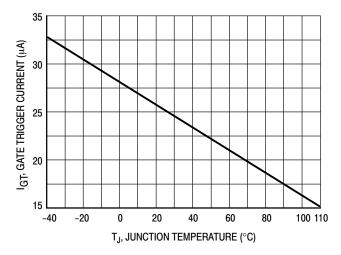


Figure 5. Typical Gate Trigger Current versus Junction Temperature

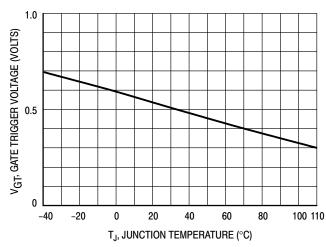


Figure 6. Typical Gate Trigger Voltage versus Junction Temperature

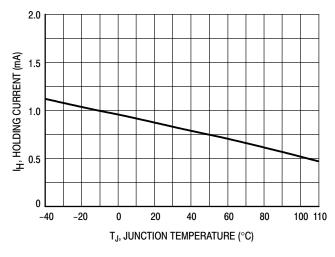


Figure 7. Typical Holding Current versus Junction Temperature

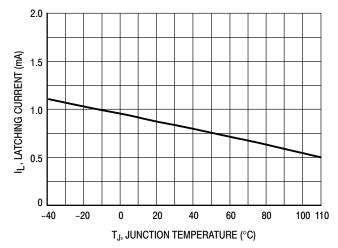
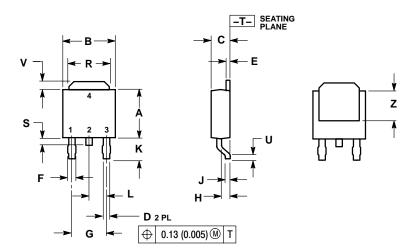


Figure 8. Typical Latching Current versus Junction Temperature

PACKAGE DIMENSIONS

DPAK CASE 369C **ISSUE O**

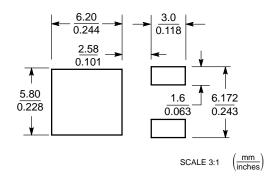


- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES MILLIMI		IETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.22
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.180 BSC		4.58 BSC	
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.180	0.215	4.57	5.45
S	0.025	0.040	0.63	1.01
U	0.020		0.51	
٧	0.035	0.050	0.89	1.27
Z	0.155		3.93	

- STYLE 4: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE

SOLDERING FOOTPRINT



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